

RoHS

COMPLIANT HALOGEN

Available

Vishay Siliconix

# Dual P-Channel 30-V (D-S) MOSFET

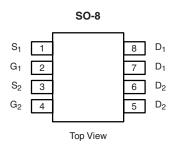
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)		
- 30	0.021 at V <sub>GS</sub> = - 10 V	- 8.3		
	0.031 at V <sub>GS</sub> = - 4.5 V	- 6.8		

#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- TrenchFET<sup>®</sup> Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

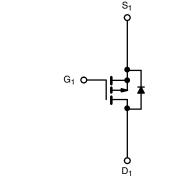
#### **APPLICATIONS**

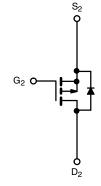
- Load Switches
  - Notebook PCs
  - Desktop PCs
- Game Stations
- Battery Switch



Ordering Information: Si4923DY-T1-E3 (Lead (Pb)-free)

Si4923DY-T1-GE3 (Lead (Pb)-free and Halogen-free)





P-Channel MOSFET

P-Channel MOSFET

Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 30		V
Gate-Source Voltage	e-Source Voltage		± 20		
	T <sub>A</sub> = 25 °C	– I <sub>D</sub>	- 8.3	- 6.2	٨
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T <sub>A</sub> = 70 °C		- 6.6	- 5.0	
Pulsed Drain Current		I <sub>DM</sub>	- 30		A
Continuous Source Current (Diode Conduction) <sup>a</sup>		l <sub>S</sub> - 1.7	- 1.7 - 0.9		
	T <sub>A</sub> = 25 °C	– P <sub>D</sub>	2.0	1.1	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.3	0.7	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	- R <sub>thJA</sub> R <sub>thJF</sub>	45	62.5	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		85	110	°C/W
Maximum Junction-to-Foot (Drain)	Steady State		26	35	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	- 1		- 3	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
		$V_{DS}$ = - 30 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C		- 25	μA		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	- 30			А	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -8.3 \text{ A}$		0.017	0.021		
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 6.8 A		0.025	0.031	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -8.3 \text{ A}$		26		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 1.7 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			45.5	70	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 15 V, $V_{GS}$ = - 10 V, $I_{D}$ = - 8.3 A		6.5			
Gate-Drain Charge	Q <sub>gd</sub>			12.6			
Turn-On Delay Time	t <sub>d(on)</sub>			15	25		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 15 V, $R_L$ = 15 $\Omega$		10	15	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 10 V, $\text{R}_\text{g}$ = 6 $\Omega$		135	210		
Fall Time	t <sub>f</sub>			80	120		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.7 A, dl/dt = 100 A/μs		70	110		

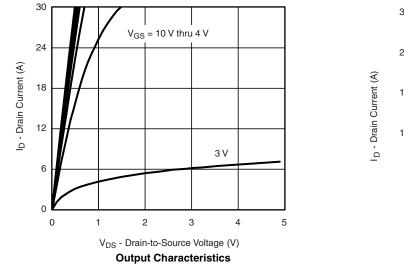
Notes:

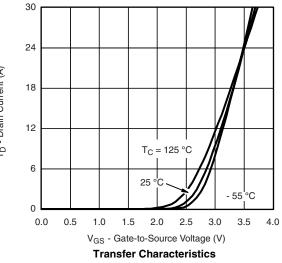
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







# Si4923DY

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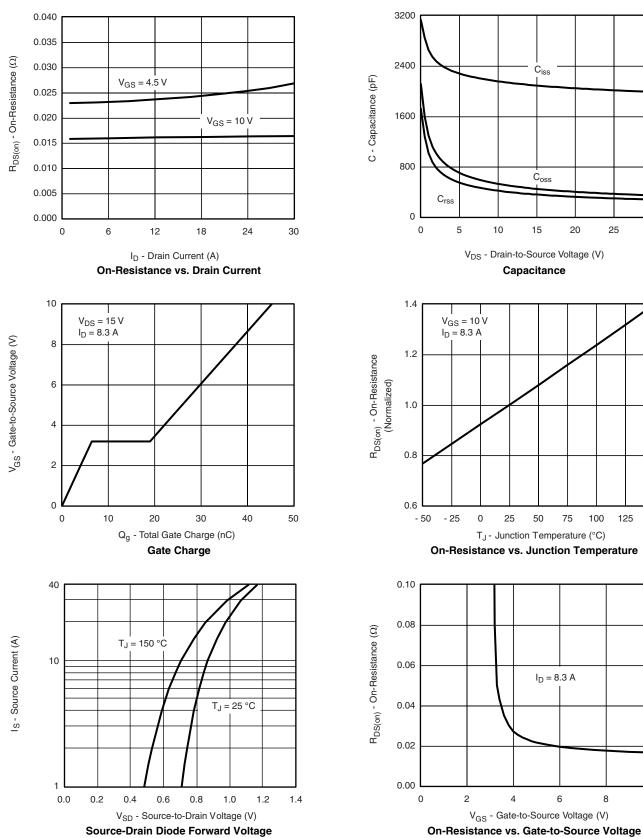
125

150

30

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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

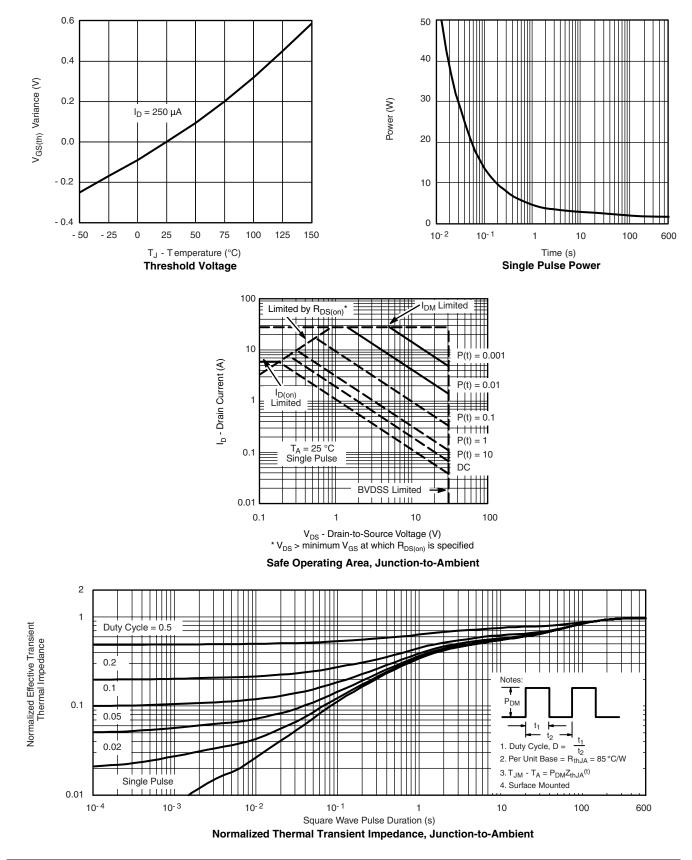


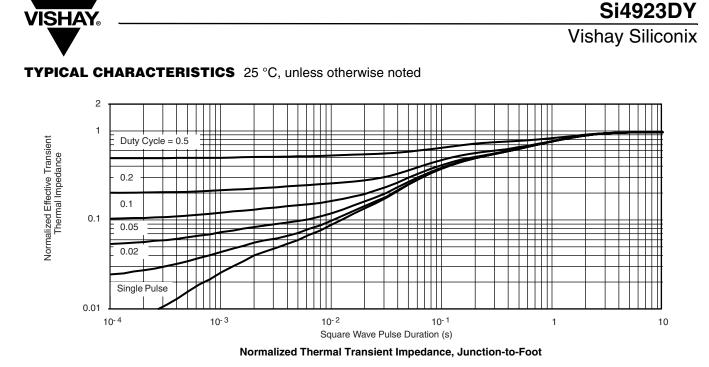
Document Number: 72069 S09-0869-Rev. C, 18-May-09 10

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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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